

PBSS5240T

40 V, 2 A PNP low VCEsat transistor

1 January 2023

Product data sheet

1. General description

PNP low V_{CEsat} transistor in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4240T

2. Features and benefits

- · Low collector-emitter saturation voltage
- High current capability
- · Improved device reliability due to reduced heat generation

3. Applications

- Supply line switching circuits
- · Battery management applications
- DC/DC converter applications
- Strobe flash units
- Heavy duty battery powered equipment (motor and lamp drivers)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	-40	V
I _C	collector current			-	-	-2	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	-3	Α
R _{CEsat}	collector-emitter saturation resistance	I_C = -500 mA; I_B = -50 mA; T_{amb} = 25 °C	[1]	-	140	220	mΩ

^[1] Device mounted on a printed-circuit board, single sided copper, tin plated, standard footprint.

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	
2	E	emitter		C
3	С	collector		В—
				E
			SOT23	sym132



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6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PBSS5240T	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBSS5240T	ZF%

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	-40	V
V _{CEO}	collector-emitter voltage	open base		-	-40	V
V _{EBO}	emitter-base voltage	open collector		-	-5	V
I _C	collector current			-	-2	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-3	Α
I _{BM}	peak base current			-	-300	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
			[2]	-	480	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
uily-a)	thermal resistance from	in free air	[1]	-	-	417	K/W
	junction to ambient		[2]	-	-	260	K/W

^{1]} Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

^{2]} Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

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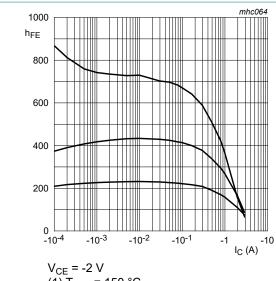
10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	I _C = -100 μA; I _E = 0 A		-40	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = -10 mA; I _B = 0 A		-40	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage (collector open)	I _E = -100 μA; I _C = 0 A		-5	-	-	V
I _{CBO}	collector-base cut-off	$V_{CB} = -30 \text{ V}; I_{E} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	-100	nA
	current	$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}; T_j = 150 \text{ °C}$		-	-	-50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -4 \text{ V; } I_{C} = 0 \text{ A; } T_{amb} = 25 \text{ °C}$		-	-	-100	nA
h _{FE}	DC current gain	V_{CE} = -2 V; I_{C} = -100 mA; T_{amb} = 25 °C		300	450	-	
		V_{CE} = -2 V; I_{C} = -500 mA; T_{amb} = 25 °C		260	350	-	
		V _{CE} = -2 V; I _C = -1 A; T _{amb} = 25 °C		210	290	-	
		V_{CE} = -2 V; I_{C} = -2 A; T_{amb} = 25 °C		100	180	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = -100 mA; I_B = -1 mA; T_{amb} = 25 °C		-	-55	-100	mV
		$I_C = -500 \text{ mA}; I_B = -50 \text{ mA}; T_{amb} = 25 ^{\circ}C$		-	-70	-110	mV
		I_C = -750 mA; I_B = -15 mA; T_{amb} = 25 °C		-	-140	-225	mV
		I _C = -1 A; I _B = -50 mA; T _{amb} = 25 °C		-	-140	-225	mV
		$I_C = -2 \text{ A}; I_B = -200 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		-	-240	-350	mV
R _{CEsat}	collector-emitter saturation resistance	$I_C = -500 \text{ mA}$; $I_B = -50 \text{ mA}$; $T_{amb} = 25 \text{ °C}$	[1]	-	140	220	mΩ
V _{BEsat}	base-emitter saturation voltage	I_C = -2 A; I_B = -200 mA; T_{amb} = 25 °C		-	-	-1.1	V
V_{BEon}	base-emitter turn-on voltage	$V_{CE} = -2 \text{ V}; I_{C} = -100 \text{ mA}; T_{amb} = 25 \text{ °C}$		-	-	-0.75	V
f _T	transition frequency	V_{CE} = -10 V; I_{C} = -100 mA; f = 100 MHz; T_{amb} = 25 °C		100	200	-	MHz
C _c	collector capacitance	V_{CB} = -10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	23	28	pF

^[1] Device mounted on a printed-circuit board, single sided copper, tin plated, standard footprint.

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(1) T_{amb} = 150 °C (2) T_{amb} = 25 °C (3) T_{amb} = -55 °C

Fig. 1. DC current gain as a function of collector current; typical values

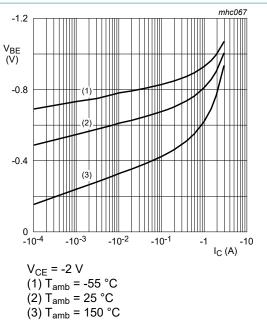
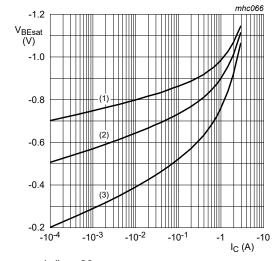


Fig. 2. Base-emitter voltage as a function of collector current; typical values



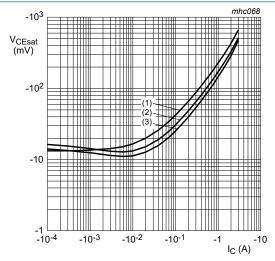
 $I_{\rm C}/I_{\rm B}=20$

(1) $T_{amb} = -55 \, ^{\circ}C$

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = 150 \, ^{\circ}C$

Fig. 3. Base-emitter saturation voltage as a function of Fig. 4. collector current; typical values



 $I_{\rm C}/I_{\rm B} = 20$

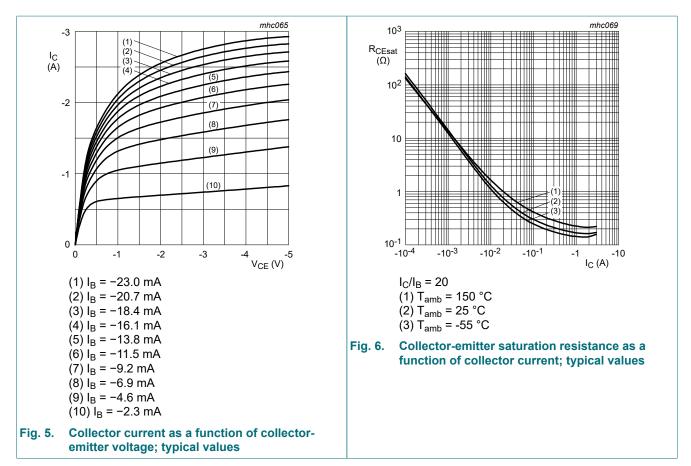
(1) $T_{amb} = 150 \, ^{\circ}C$

(2) $T_{amb} = 25 \, ^{\circ}C$

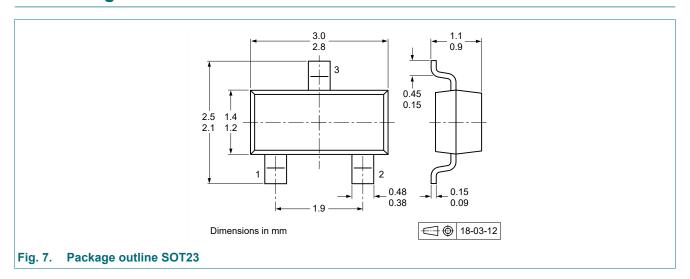
(3) $T_{amb} = -55 \, ^{\circ}C$

Collector-emitter saturation voltage as a function of collector current; typical values

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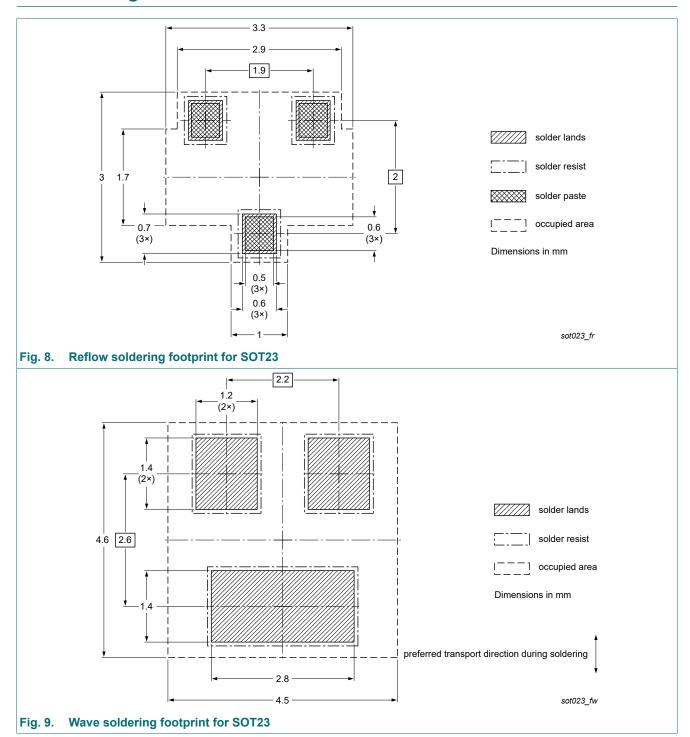


11. Package outline



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12. Soldering



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13. Revision history

Table 8. Revision history

Tubic o. Itevision in	otor y			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS5240T v.3	20230101	Product data sheet	-	PBSS5240T v.2
Modifications:	 Characteristics: Characteristics: The format of the Nexperia. Legal texts have 	•	ed n mA to A and mV to \ esigned to comply with ecompany name where	the identity guidelines of
PBSS5240T v.2	20040115	Product data sheet	-	PBSS5240T v.1
PBSS5240T v.1	20011031	Product data sheet	-	-

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14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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